

1. General description

The TJA1083 FlexRay node transceiver is compliant with the FlexRay Electrical Physical Layer specification V3.0.1 (see [Ref. 1](#page-36-0)). In order to meet JASPAR the equirements, it implements the 'Increased voltage amplitude transmitter' functional class. It is primarily intended for communication systems operating at between 2.5 Mbit/s and 10 Mbit/s, and provides an advanced interface between the protocol controller and the physical bus in a FlexRay network. The TJA1083 offers an optimized solution for Electronic Control Unit (ECU) applications that do not need enhanced power management and are typically switched by the ignition or activated by a dedicated wake-up line.

The TJA1083 provides a differential transmit capability to the network and a differential receive capability to the FlexRay controller. It offers excellent ElectroMagnetic Compatibility (EMC) performance as well as high ElectroStatic Discharge (ESD) protection.

The TJA1083 actively monitors system performance using dedicated error and status information (readable by any microcontroller), as well as internal voltage and temperature monitoring.

2. Features and benefits

2.1 Optimized for time triggered communication systems

- Compliant with Electrical Physical Layer specification V3.0.1
- Meets JASPAR requirements as described in the 'Bus driver increased voltage amplitude transmitter' functional class
- Automotive product qualification in accordance with AEC-Q100
- Data transfer rates from 2.5 Mbit/s to 10 Mbit/s
- Supports 60 ns minimum bit time at 400 mV differential input voltage
- Very low ElectroMagnetic Emission (EME) to support unshielded cable
- **Differential receiver with high common-mode range for excellent ElectroMagnetic** Immunity (EMI)
- Auto I/O level adaptation to host controller supply voltage V_{10}
- Can be used in 14 V, 24 V and 48 V powered systems
- Instant transmitter shut-down interface (BGE pin)

2.2 Low-power management

- Very low current consumption in Standby mode
- Remote wake-up via a wake-up pattern or dedicated FlexRay data frames on the bus lines

2.3 Diagnosis and robustness

- Enhanced supply voltage monitoring for V_{CC} and V_{IO}
- \blacksquare Two error diagnosis modes:
	- Status register readout via the Serial Peripheral Interface (SPI)
	- ◆ Simple error indication via pin ERRN
- **Overtemperature detection**
- Short-circuit detection on bus lines
- **Power-on flag**
- Clamping diagnosis for pins TXEN and BGE
- Bus pins protected against ± 6 kV ESD pulses according to IEC61000-4-2 and ± 8 kV according to HBM
- Bus pins protected against transients in automotive environment (according to ISO 7637 class C)
- Bus pins short-circuit proof to battery voltage (14 V, 24 V and 48 V) and ground
- **Maximum differential voltage between pins BP or BM and any other pin of** ± 60 **V**
- \blacksquare Bus lines remain passive when the transceiver is not powered
- No reverse currents from the digital input pins to V_{10} or V_{CC} when the transceiver is not powered

2.4 Functional classes according to FlexRay Electrical Physical Layer specification V3.0.1

- Bus driver increased voltage amplitude transmitter
- Bus driver bus guardian control interface
- Bus driver logic level adaptation
- Bus driver remote wake-up

3. Ordering information

Table 1. Ordering information

4. Block diagram

5. Pinning information

5.1 Pinning

5.2 Pin description

Table 2. Pin description

6. Functional description

6.1 Power modes

The TJA1083 features three power modes: Normal, Standby and Power-off. Normal and Standby modes can be selected via the STBN input (HIGH for Normal mode) once the transceiver has been powered up. See [Table 3](#page-4-0) for a detailed description of pin signaling in the three power modes.

FlexRay node transceiver

Table 3. Pin signaling in the different power modes

[1] The wake flag is set if a valid wake-up event is detected while switching to Standby mode.

[2] The wake flag is set if a valid wake-up event is detected.

[3] $V_{uvd(VCC)} > V_{CC} > V_{th(det)POR}$.

[4] Pins ERRN and RXD reflect the state of the wake flag prior to the V_{CC} undervoltage event.

[5] The internal signals at pins STBN, BGE and TXD are set LOW; the internal signals at pins TXEN, SCLK and SCSN are set HIGH.

[6] Except when $V_{CC} = 0$; in this case BP and BM are floating.

6.1.1 Normal mode

In Normal mode, the transceiver transmits and receives data via the bus lines BP and BM. The transmitter and the normal receiver are enabled, along with the undervoltage detection function. The timing diagram for Normal mode is illustrated in [Figure 3](#page-5-0).

[Table 4](#page-5-1) describes the behavior of the transmitter in Normal mode, when the temperature flag (TEMP HIGH) is not set and with no time-out on pin TXEN. Transmitter behavior is illustrated in [Figure 13](#page-26-0).

Table 4. Transmitter operation in Normal mode

The transmitter is activated during the first LOW level on pin TXD while pin BGE is HIGH and pin TXEN is LOW.

In Normal mode, the normal receiver output is connected directly to pin RXD (see [Table 5](#page-5-2)). Receiver behavior is illustrated in [Figure 14.](#page-27-0)

When V_{IO} and V_{CC} are within their operating ranges, pin ERRN indicates the status of the error flag. See [Section 6.8](#page-13-0) for a detailed description of error signaling in Normal mode.

6.1.1.1 Bus activity and idle detection

In Normal mode, bus activity and bus idle are detected as follows:

- **•** Bus activity is detected when the absolute differential voltage on the bus lines is higher than $|V_{i(dif)det(act)}|$ for $t_{det(act)(bus)}$:
	- If the differential voltage on the bus lines is lower than V_{IL(dif)} after bus activity has been detected, pin RXD switches LOW.
	- $-$ If the differential voltage on the bus lines is higher than $V_{H(dif)}$ after bus activity has been detected, pin RXD remains HIGH.
- **•** Bus idle is detected when the absolute differential voltage on the bus lines is lower than $|V_{\text{ifdif1}det(act)}|$ for $t_{\text{det}(idle)(bus)}$. This results in pin RXD being switched HIGH or staying HIGH.

6.1.2 Standby mode

Standby mode is a low-power mode featuring very low current consumption. In Standby mode, the transceiver is unable to transmit or receive data since both the transmitter and the normal receiver are switched off. The low-power receiver is activated to monitor the bus for wake-up activity, provided an undervoltage has not been detected on pin V_{CC} .

The low-power receiver is deactivated if an undervoltage is detected on pin V_{CC} - with the result that the wake flag is not set if a wake-up pattern or dedicated data frame is received.

Pins ERRN and RXD indicate the status of the wake flag when V_{1O} and V_{CC} are within their operating ranges. See [Table 3](#page-4-0) for a description of pins ERRN and RXD when an undervoltage is detected on pin V_{IO} or pin V_{CC} .

The status register cannot be read via the SPI interface if an undervoltage is detected on pin V_{10} .

The BGE input has no effect in Standby mode.

6.1.3 Power-off mode

The transmitter and the two receivers (normal and low-power) are deactivated in Power-off mode. As a result, the wake flag is not set if a wake-up pattern or dedicated data frame is received. If the voltage at V_{CC} rises above $V_{th(rec)PN}$, the transceiver switches to Standby mode and the digital section is reset. If V_{CC} subsequently drops below $V_{th(det)POR}$, the transceiver reverts to Power-off mode (see [Section 6.2](#page-8-0)).

The status register cannot be read via the SPI interface in Power-off mode.

6.1.4 State transitions

[Figure 4](#page-7-0) shows the TJA1083 state transition diagram. The timing diagram for the ERRN indication signal during transitions between Normal and Standby modes, when the error flag is set and the wake flag is not set, is illustrated in [Figure 5](#page-7-1) and described in [Table 6.](#page-8-1)

FlexRay node transceiver

TJA1083 **All information provided in this document is subject to legal disclaimers.** © NXP B.V. 2012. All rights reserved.

Table 6. State transitions

 indicates the action that initiates a transaction; 1 and 2 are the consequences of a transaction.

[1] See [Table 7](#page-12-0) for set and reset conditions of all flags.

6.2 Power-up and power-down behavior

6.2.1 Power-up

The TJA1083 has two supply pins: V_{CC} (+5 V) and V_{IO} (for the voltage level adaptation). The ramp up of the different power supplies can vary, depending on the state or value of a number of signals and parameters. The power-up behavior of the TJA1083 is not affected by the sequence in which power is supplied to these pins or by the voltage ramp up.

As an example, [Figure 6](#page-9-0) shows one possible power supply ramp-up scenario. The digital section of the TJA1083 is supplied by V_{CC} . The voltage on pin V_{CC} ramps up before the voltage on pin V_{IO} . As long as the voltage on V_{CC} remains below the power-on reset recovery threshold, $V_{th(rec)POR}$, the internal state machine is inactive and the transceiver is totally passive, remaining in Power-off mode. As soon as the voltage rises above the Vth(rec)POR threshold, the internal state machine starts running, setting the PWON flag and switching the TJA1083 to Standby mode. This initializes the V_{CC} and V_{IO} under-voltage flags to the set state (since both V_{CC} and V_{IO} are actually in undervoltage state just after power-on).

Once both V_{IO} and V_{CC} have reached their operating ranges, the under-voltage flags are reset. The operating mode is then determined by the level on STBN (the TJA1083 switches to Normal mode if STBN is HIGH and remains in Standby mode if STBN is LOW), provided V_{10} and V_{CC} are above their respective undervoltage recovery levels $(V_{uvr(VIO)}$ and $V_{uvr(VCC)}$).

FlexRay node transceiver

6.2.2 Power-down

The behavior of the TJA1083 during power-down is illustrated in [Figure 7](#page-9-1).

6.3 Remote wake-up

6.3.1 Bus wake-up via wake-up pattern

A valid remote wake-up event occurs when a wake-up pattern is received. A wake-up pattern consists of at least two consecutive wake-up symbols. A wake-up symbol comprises a DATA_0 phase lasting longer than $t_{\text{det(wake)DATA}-0}$ followed by an idle phase lasting longer than $t_{\text{det(wake)idle}}$, provided both wake-up symbols occur within a time span of $t_{\text{det(wake)tot}}$ (see [Figure 8\)](#page-10-0). The transceiver also wakes up if DATA_1 phases are substituted for the idle phases.

See [Ref. 1](#page-36-0) for more details of the wake-up mechanism.

6.3.2 Bus wake-up via dedicated FlexRay data frame

The TJA1083 wake flag is set when a dedicated data frame emulating a valid wake-up pattern, as shown in [Figure 9,](#page-11-0) is received.

The DATA_0 and DATA_1 phases of the emulated wake-up symbol are interrupted by the Byte Start Sequence (BSS) preceding each byte in the data frame. With a data rate of 10 Mbit/s, the interruption has a maximum duration of 130 ns and does not prevent the transceiver from recognizing the wake-up pattern in the payload.

For longer interruptions at lower data rates (5 Mbit/s and 2.5 Mbit/s), the wake-up pattern should be used (see [Section 6.3.1](#page-10-1)).

The wake flag is not set if an invalid wake-up pattern is received. See [Ref. 1](#page-36-0) for more details on invalid wake-up patterns.

6.4 Bus error detection

The TJA1083 detects the following bus errors during transmission:

- **•** Short-circuit BP to BM at the ECU connector or on the bus
- **•** Short-circuit BP to GND at the ECU connector or on the bus
- **•** Short-circuit BM to GND at the ECU connector or on the bus
- Short-circuit BP to V_{CC} at the ECU connector or on the bus
- Short-circuit BM to V_{CC} at the ECU connector or on the bus

The bus error flag is not set when a wake-up pattern or a FlexRay Collision Avoidance Symbol (CAS) is being transmitted or received.

6.5 Fail silent behavior

Three mechanisms guarantee the 'fail silent' behavior of the TJA1083:

- The TXEN clamped flag is set if pin TXEN goes LOW for longer than t_{detCl} (TXEN) in Normal mode; the transmitter is disabled.
- The BGE clamped flag is set if pin BGE goes HIGH for longer than t_{detCl(BGF)} in Normal mode; no action is taken.
- **•** If a loss-of-ground occurs at the transceiver, resulting in the TJA1083 switching to Power-off mode, no current flows out of the digital input pins (TXD, TXEN, BGE, STBN, SCLK, SCSN); see [Table 3](#page-4-0) for details of the behavior of the bus pins.

6.6 TJA1083 flags

The TJA1083 has 11 status/error flags. These are described in [Table 7](#page-12-0).

Table 7. TJA1083 flags and set/reset conditions

[1] All flags, except for the PWON flag, are reset after a power-on reset.

[2] If an undervoltage has not been detected on pin V_{CC} .

 $[3]$ If STBN = LOW.

[4] If BGE = HIGH, the Normal mode flag is set, the TEMP HIGH flag is not set and the TXEN clamped flag is not set.

- [5] Flag can only be set or reset in Normal mode or on leaving Normal mode.
- $[6]$ If STBN = HIGH.
- [7] If STBN = HIGH in SPI mode
- [8] The SPI error flag is set when:

a) more than 16 falling edges occur on pin SCLK while pin SCSN = LOW

b) less than 16 falling edges occur on pin SCLK while pin SCSN = LOW.

6.7 TJA1083 status register

The TJA1083 contains a 16-bit status register, of which bits S0 to S4 reflect the state of the status flags, bits S5 to S10 reflect the state of the error flags and bit S15 is a parity bit. All flags can be individually read out on pin SDO via a 16-bit SPI interface when the transceiver is configured in SPI mode. The status register bits are described in [Table 8.](#page-13-1)

FlexRay node transceiver

Table 8. TJA1083 status register

[1] Also cleared during Power-off.

6.8 Error signaling

The TJA1083 provides two modes for error indication:

- **•** Simple error indication mode
- **•** SPI mode (default mode)

SPI mode is active on power-up.

To switch to simple error indication mode, SCSN must be held LOW (connected to GND) and SCLK held HIGH (connected to V_{1O}) for longer than $t_{det(L)(SCLK)}$ (provided a V_{1O} undervoltage has not occurred). When the TJA1083 is in simple error indication mode, a rising edge on SCSN initiates a transition to SPI mode (again provided a V_{1O} undervoltage has not occurred); see [Figure 10.](#page-14-0)

If a V_{10} undervoltage condition is detected, it is not possible to switch between SPI mode and simple error indication mode.

6.8.1 SPI mode

The error flag information in the status register is latched in SPI mode. This means that the status bit is reset once the status register has been completely read (provided the corresponding error flag has been reset). If an error condition is detected in Normal mode, pin ERRN goes LOW (provided one of the error bits, S5 to S10, is set). Pin ERRN goes HIGH again once all the error bits have been reset.

6.8.2 Simple error indication mode

If an error condition is detected in Normal mode, pin ERRN goes LOW once the relevant error flag has been set. Pin ERRN stays stable for at least t_{ERRNL(min)} and goes HIGH again when all error conditions have been cleared and all flags have been reset. Error flags are not latched. It is not possible to read-out the status bits in this mode.

6.9 SPI interface

The TJA1083 includes a 16-bit SPI interface to enable a host to read the status register when the transceiver is in SPI mode (see [Section 6.8\)](#page-13-0).

While pin SCSN is HIGH, the SDO output is in a high-impedance state. To begin a status register readout, the host must force pin SCSN LOW. This action causes the SDO pin to output a LOW level by default. The data on pin SDO is then shifted out on the rising edge of the clock signal on pin SCLK.

The status bits shifted out on pin SDO are active HIGH. The status bits are refreshed and pin SDO returned to a high-impedance state once the status register has been read successfully (after exactly 16 clock cycles) and SCSN has been forced HIGH again. Clock signals on SCLK are ignored while SCSN is HIGH. The timing diagram for the SPI readout is illustrated in [Figure 11.](#page-15-0)

The SLCK period ranges from 500 ns to 100 μ s (10 kbit/s to 2 Mbit/s).

If SCSN remains LOW for longer than 16 clock cycles, it is recognized as an SPI error. When this happens, the SPI error flag is set and pin SDO goes to a high-impedance state until the next falling edge on pin SCSN.

An SPI error is also assumed if fewer than 16 clock cycles are received while SCSN is LOW. If this happens, the SPI error flag is set.

All status bits are refreshed once the status register has been successfully read.

When the transceiver is in simple error indication mode the SDO output is in a high-impedance state and pin SCSN is in pull-down mode. In SPI mode pin SCSN is in pull-up mode.

7. Limiting values

Table 9. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). All voltages are referenced to GND.

Table 9. Limiting values *…continued*

In accordance with the Absolute Maximum Rating System (IEC 60134). All voltages are referenced to GND.

[1] According to ISO7637, test pulse 1, class C; verified by an external test house.

[2] According to ISO7637, test pulse 2a, class C; verified by an external test house.

[3] According to ISO7637, test pulse 3a, class C; verified by an external test house.

[4] According to ISO7637, test pulse 3b, class C; verified by an external test house.

[5] In accordance with IEC 60747-1. An alternative definition of T_{vi} is: T_{vj} = T_{amb} + P × R_{th(j-a)}, where R_{th(j-a)} is a fixed value used in the calculation of T_{vj}. The rating for T_{vj} limits the allowable combinations of power dissipation (P) and ambient temperature (T_{amb}).

[6] IEC61000-4-2: C = 150 pF; R = 330 Ω ; verified by an external test house; the test results were equal to or better than ± 6 kV (unaided).

[7] HBM: C = 100 pF; R = 1.5 k Ω .

[8] MM: C = 200 pF; L = 0.75 μ H; R = 10 Ω .

[9] CDM: $R = 1 \Omega$.

8. Thermal characteristics

Table 10. Thermal characteristics

9. Static characteristics

Table 11. Static characteristics

All parameters are guaranteed for V_{CC} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{Vj} = –40 °C to +150 °C; R_{bus} = 40 Ω *to 55* \varOmega and C_{bus} = 100 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the *IC.*

All parameters are guaranteed for V_{CC} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = -40 °C to +150 °C; R_{bus} = 40 Ω *to 55 and Cbus = 100 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.*

All parameters are guaranteed for V_{CC} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = -40 °C to +150 °C; R_{bus} = 40 Ω *to 55 and Cbus = 100 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.*

All parameters are guaranteed for V_{CC} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{Vj} = –40 °C to +150 °C; R_{bus} = 40 Ω *to 55* \varOmega and C_{bus} = 100 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the *IC.*

All parameters are guaranteed for V_{CC} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = -40 °C to +150 °C; R_{bus} = 40 Ω *to 55 and Cbus = 100 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.*

[1] Guaranteed by design.

[2] V_{cm} is the BP/BM common mode voltage.

[3] $Z_{o(TX)(eq)} = 50 \Omega \times (V_{bus(100)} - V_{bus(40)})/(2.5 \times V_{bus(40)} - V_{bus(100)})$, where: $V_{bus(100)}$ = the differential output voltage on a load of 100 Ω and 100 pF in parallel. $V_{\text{bus}(40)}$ = the differential output voltage on a load of 40 Ω and100 pF in parallel, when driving a DATA_1.

[4] $R_{\rm sc}$ is the short-circuit resistance; voltage difference between bus pins BP and BM is 60 V max.

[5] R_{sc} is the short-circuit resistance between BP and BM.

[6] t_{sc} is the minimum duration of the short-circuit

10. Dynamic characteristics

Table 12. Dynamic characteristics

All parameters are guaranteed for V_{CC} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = -40 °C to +150 °C; R_{bus} = 40 Ω and *Cbus = 100 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.*

Table 12. Dynamic characteristics *…continued*

All parameters are guaranteed for V_{CC} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vj} = -40 °C to +150 °C; R_{bus} = 40 Ω *and Cbus = 100 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.*

Table 12. Dynamic characteristics *…continued*

All parameters are guaranteed for V_{CC} = 4.45 V to 5.25 V; V_{IO} = 2.55 V to 5.25 V; T_{vi} = -40 °C to +150 °C; R_{bus} = 40 Ω and *Cbus = 100 pF unless otherwise specified. All voltages are defined with respect to ground; positive currents flow into the IC.*

[1] Sum of TXD rise and fall times (20 % to 80 %); $t_{r(TXD)} + t_{f(TXD)} = \text{max. 9 ns.}$

- [2] See [Figure 13](#page-26-0).
- [3] V_{cm} is the BP/BM common mode voltage.
- [4] See [Figure 14](#page-27-0).
- [5] See [Figure 13](#page-26-0).
- [6] Guaranteed by design.
- [7] $V_{\text{dif}} = V_{\text{BP}} - V_{\text{BM}}$.
- [8] See [Figure 8.](#page-10-0)
- [9] See [Figure 9.](#page-11-0)
- [10] See [Figure 11.](#page-15-0)

[11] Load at end of 50 Ω microstrip with a propagation delay of 1 ns; 20 % to 80 % and 80 % to 20 %.

@ NXP B.V. 2012. All rights reserved. © NXP B.V. 2012. All rights reserved. 26 of 41

Fig 12. Detailed timing diagram

FlexRay node transceiver

FlexRay node transceiver

11. Test information

12. Package outline

Fig 17. Package outline SOT402-1 (TSSOP14)

TJA1083 **All information provided in this document is subject to legal disclaimers.** © NXP B.V. 2012. All rights reserved.

13. Soldering of SMD packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering ICs can be found in Application Note *AN10365 "Surface mount reflow soldering description"*.

13.1 Introduction to soldering

Soldering is one of the most common methods through which packages are attached to Printed Circuit Boards (PCBs), to form electrical circuits. The soldered joint provides both the mechanical and the electrical connection. There is no single soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and Surface Mount Devices (SMDs) are mixed on one printed wiring board; however, it is not suitable for fine pitch SMDs. Reflow soldering is ideal for the small pitches and high densities that come with increased miniaturization.

13.2 Wave and reflow soldering

Wave soldering is a joining technology in which the joints are made by solder coming from a standing wave of liquid solder. The wave soldering process is suitable for the following:

- **•** Through-hole components
- **•** Leaded or leadless SMDs, which are glued to the surface of the printed circuit board

Not all SMDs can be wave soldered. Packages with solder balls, and some leadless packages which have solder lands underneath the body, cannot be wave soldered. Also, leaded SMDs with leads having a pitch smaller than ~0.6 mm cannot be wave soldered, due to an increased probability of bridging.

The reflow soldering process involves applying solder paste to a board, followed by component placement and exposure to a temperature profile. Leaded packages, packages with solder balls, and leadless packages are all reflow solderable.

Key characteristics in both wave and reflow soldering are:

- **•** Board specifications, including the board finish, solder masks and vias
- **•** Package footprints, including solder thieves and orientation
- **•** The moisture sensitivity level of the packages
- **•** Package placement
- **•** Inspection and repair
- **•** Lead-free soldering versus SnPb soldering

13.3 Wave soldering

Key characteristics in wave soldering are:

- **•** Process issues, such as application of adhesive and flux, clinching of leads, board transport, the solder wave parameters, and the time during which components are exposed to the wave
- **•** Solder bath specifications, including temperature and impurities

13.4 Reflow soldering

Key characteristics in reflow soldering are:

- **•** Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see Figure 18) than a SnPb process, thus reducing the process window
- **•** Solder paste printing issues including smearing, release, and adjusting the process window for a mix of large and small components on one board
- **•** Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature) and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic). In addition, the peak temperature must be low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with Table 13 and 14

Table 13. SnPb eutectic process (from J-STD-020C)

Table 14. Lead-free process (from J-STD-020C)

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see Figure 18.

For further information on temperature profiles, refer to Application Note *AN10365 "Surface mount reflow soldering description"*.

14. Appendix

14.1 Differences between TJA1082 and TJA1083

The main differences between the TJA1083 and the TJA1082 are:

- **•** The TJA1083 is EPL V3.0.1 compliant whereas the TJA1082 is EPL V2.1 Rev. B compliant
- **•** The TJA1083 is JASPAR compliant (minimum transmitter output voltage of 900 mV)
- **•** The TJA1083 has a higher pulse immunity (ISO7637)
- **•** The TJA1083 has improved EMC behavior
- **•** The bus load conditions for the static and dynamic characteristics are different in EPL V3.0.1 compared to EPL V2.1 Rev. B: 40 Ω to 55 Ω for the static characteristics instead of 40 Ω and 40 Ω for the dynamic characteristics instead of 45 Ω .

FlexRay node transceiver

14.2 Implementation of EPL 3.0.1 requirements in the TJA1083

Table 15. EPL 3.0.1 implementation in TJA1083

EPL 3.0.1				TJA1083			
	Min	Max	Unit	Symbol	Min	Max	Unit
dBDRxAsym		5	ns	$ \Delta t_{d(bus-RXD)} $	$\pmb{0}$	5	ns
dBDRx10		75	ns	$t_{d(bus-RXD)}$	\blacksquare	75	ns
dBDRx01	÷,	75	ns	$t_{d(bus-RXD)}$	\blacksquare	75	ns
dBDRxai	50	275	ns	$t_{\text{det(idle)}(bus)} + t_{\text{d(bus-RXD)}}$	100	275	ns
dBDRxia	100	325	ns	$t_{\text{det}(\text{act})(\text{bus})} + t_{\text{d}(\text{bus-RXD})}$	100	325	ns
dBDTxAsym		4	ns	$ \Delta t_{d(TXD-bus)} $	$\pmb{0}$	4	ns
dBDTx10	$\qquad \qquad \blacksquare$	75	ns	$t_{d(TXD-bus)}$	\blacksquare	60	ns
dBDTx01	$\frac{1}{2}$	75	ns	$t_{d(TXD-bus)}$	\blacksquare	60	ns
dBDTxai	$\frac{1}{2}$	75	ns	t _d (TXEN-busidle)	$\overline{}$	75	ns
dBDTxia	$\frac{1}{2}$	75	ns	$t_{d(TXEN-busact)}$	$\overline{}$	75	ns
dBusTxai	$\frac{1}{2}$	30	ns	$t_{r(bus)(act-idle)}$	\blacksquare	30	ns
dBusTxia	ä,	30	ns	$t_{f(bus)(idle-act)}$	\blacksquare	30	ns
dBusTx01	6	18.75	ns	$t_{r(\text{dif})(bus)}$	6	18.75	ns
dBusTx10	6	18.75	ns	$t_{f(di)(bus)}$	6	18.75	ns
uBDTxactive	600	2000	mV	$V_{OH(dif)}$	900	2000	mV
u BDT x_{idle}	0	30	mV	$ V_{o(idle)(dif)} $	0	25	mV
uV _{DIG-OUT-HIGH}	80	100	$\%$	$V_{OH(RXD)}$	$V_{IO} - 0.4$	V_{IO}	V
				VOH(ERRN)	$V_{IO} - 0.4$	V_{IO}	V
uV _{DIG-OUT-LOW}	$\frac{1}{2}$	20	$\%$	$V_{OL(RXD)}$		0.4	$\mathsf V$
				$V_{OL(ERRN)}$	$\overline{}$	0.4	V
uV _{DIG-IN-HIGH}	$\frac{1}{2}$	70	$\%$	$V_{IH(TXEN)}$	$0.7V_{10}$	5.5	$\mathsf V$
				V _{IH} (STBN)	0.7V ₁₀	5.5	V
				$V_{IH(BGE)}$	0.7V ₁₀	5.5	V
uV _{DIG-IN-LOW}	30		$\%$	$V_{IL(TXEN)}$	-0.3	$+0.3V_{10}$	V
				$V_{IL(STBN)}$	-0.3	$+0.3V_{10}$	V
				$V_{IL(BGE)}$	-0.3	$+0.3V10$	V
uData0	-300	-150	mV	$V_{IL(dif)}$	-300	-150	mV
uData1	150	300	mV	$V_{IH(\underline{dif})}$	150	300	mV
uData1- uData0	-30	30	mV	$ \Delta V_{i(dif)(H-L)} $	\blacksquare	30	mV
dBDActivityDetection	100	250	ns	$t_{\text{det}(\text{act})(\text{bus})}$	100	250	ns
dBDIdleDetection	50	200	ns	$t_{\text{det(idle)}(bus)}$	100	200	ns
R_{CM1} , R_{CM2}	10	40	k Ω	$R_{i(BP)}$, $R_{i(BM)}$	10	40	kΩ
uCM	-10	15	V	V_{cm} [1]	-10	$+15$	V
iBM GNDShortMax	$\overline{}$	60	mA	$ I_{O(SC)(BM)} $	$\qquad \qquad \blacksquare$	60	mA
iBP GNDShortMax	$\qquad \qquad \blacksquare$	60	mA	$ I_{O(SC)(BP)} $	$\frac{1}{2}$	60	mA
iBM _{BAT48ShortMax}	$\overline{}$	72	mA	$ I_{O(\rm sc)(\rm BM)} $	\blacksquare	72	mA
iBP _{BAT48ShortMax}	L,	72	mA	$ I_{O(SC)(BP)} $	\blacksquare	72	mA
iBMBAT27ShortMax	$\overline{}$	60	mA	$ I_{O(\rm{sc})(\rm{BM})} $	$\qquad \qquad \blacksquare$	60	mA

TJA1083 All information provided in this document is subject to legal disclaimers. © NXP B.V. 2012. All rights reserved.

FlexRay node transceiver

Table 15. EPL 3.0.1 implementation in TJA1083

TJA1083 All information provided in this document is subject to legal disclaimers. © NXP B.V. 2012. All rights reserved.

FlexRay node transceiver

[1] V_{cm} is the BP/BM common mode voltage, $(V_{BP} + V_{BM})/2$, and is specified in conditions column of parameters $V_{HH(dif)}$ and $V_{H_U(dif)}$ for pins BP and BM; see [Table 11.](#page-17-0) V_{cm} is tested on a receiving bus driver with a transmitting bus driver that has a ground offset voltage in the range -12.5 V to $+12.5$ V and transmits a 50/50 pattern.

[2] Min. value: V_{o(idle)(BP)} = V_{o(idle)(BM)} = 0.4V_{CC} = 0.4 × 4.5 V = 1800 mV; max value: V_{o(idle)(BP)} = V_{o(idle)(BM)} = 0.6V_{CC} = 0.6 × 5.25 V = 3150 mV; the nominal voltage is 2500 mV.

[3] The normal voltage is 0 mV.

[4] Power-off mode.

15. Abbreviations

16. References

- **[1] EPL —** FlexRay Communications System Electrical Physical Layer Specification Version 3.0.1 (expected to be released by the end of 2009)
- **[2] AN** Application hint AN10365 Surface mount reflow soldering description

17. Revision history

18. Legal information

18.1 Data sheet status

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status
information is available on the Intern

18.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

18.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications — This NXP Semiconductors product has been qualified for use in automotive applications. The product is not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at<http://www.nxp.com/profile/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

18.4 Licenses

NXP ICs with FlexRay functionality

This NXP product contains functionality that is compliant with the FlexRay specifications.

These specifications and the material contained in them, as released by the FlexRay Consortium, are for the purpose of information only. The FlexRay Consortium and the companies that have contributed to the specifications shall not be liable for any use of the specifications.

The material contained in these specifications is protected by copyright and other types of Intellectual Property Rights. The commercial exploitation of the material contained in the specifications requires a license to such Intellectual Property Rights.

These specifications may be utilized or reproduced without any modification, in any form or by any means, for informational purposes only. For any other purpose, no part of the specifications may be utilized or reproduced, in any form or by any means, without permission in writing from the publisher.

The FlexRay specifications have been developed for automotive applications only. They have neither been developed nor tested for non-automotive applications.

The word FlexRay and the FlexRay logo are registered trademarks.

18.5 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

19. Contact information

For more information, please visit: **http://www.nxp.com**

For sales office addresses, please send an email to: **salesaddresses@nxp.com**

Product data sheet 40 of 41 **Rev. 1 — 10 October 2012** 40 of 41

FlexRay node transceiver

20. Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2012. All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 10 October 2012 Document identifier: TJA1083

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[NXP](https://www.mouser.com/nxp-semiconductors): [TJA1083TTJ](https://www.mouser.com/access/?pn=TJA1083TTJ)

ООО "ЛайфЭлектроникс" "LifeElectronics" LLC

ИНН 7805602321 КПП 780501001 Р/С 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 30101810900000000703 БИК 044030703

 Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

 Мы предлагаем:

- *Конкурентоспособные цены и скидки постоянным клиентам.*
- *Специальные условия для постоянных клиентов.*
- *Подбор аналогов.*
- *Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.*
- *Приемлемые сроки поставки, возможна ускоренная поставка.*
- *Доставку товара в любую точку России и стран СНГ.*
- *Комплексную поставку.*
- *Работу по проектам и поставку образцов.*
- *Формирование склада под заказчика.*
- *Сертификаты соответствия на поставляемую продукцию (по желанию клиента).*
- *Тестирование поставляемой продукции.*
- *Поставку компонентов, требующих военную и космическую приемку.*
- *Входной контроль качества.*
- *Наличие сертификата ISO.*

 В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- *Регистрацию проекта у производителя компонентов.*
- *Техническую поддержку проекта.*
- *Защиту от снятия компонента с производства.*
- *Оценку стоимости проекта по компонентам.*
- *Изготовление тестовой платы монтаж и пусконаладочные работы.*

 Tел: +7 (812) 336 43 04 (многоканальный) Email: org@lifeelectronics.ru

www[.lifeelectronics.ru](http://lifeelectronics.ru/)